

BAV16W

Technical Data Data Sheet N0589, Rev. A



BAV16W SCHOTTKY BARRIER DIODE



Features

- Fast switching speed
- Surface mount package ideally suited for automatic insertion
- For general purpose switching applications
- High conductance
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram

Cathode Anode

Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams(approx.)
- Marking: T6

Maximum Ratings @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Limit	Units
Non-Repetitive Peak Reverse Voltage	VRM	75	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V
RMS Reverse Voltage	V _{R(RMS)}	71	V
Forward Continuous Current	I _{FM}	300	mA
Average Rectified Output Current	lo	150	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	2	A
Power Dissipation	Pd	400	mW
Typical Thermal Resistance Junction to Ambient	R _{0JA}	250	°C/W
Junction Temperature Range	TJ	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

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Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	Мах	Unit	Test Condition
Forward Voltage*	V _F	0.715 0.855 1.0 1.25	V	I _F =1mA I _F =10mA I _F =50mA I _F =150mA
Reverse Leakage Current*	I _R	1	μA	V _R =75V
Capacitance between terminals	Ст	2	pF	V _R =0V,f=1.0MHz
Reverse recovery time	t _{rr}	4	ns	$I_{F}=I_{R}=10mA$, $I_{rr}=0.1 \times I_{R}$, $R_{L}=100\Omega$

* Pulse width < 300 μ s, duty cycle < 2%

Ratings and Characteristics Curves



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Mechanical Dimensions SOD-123







	Millim	neters	Inches	
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
с	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF.		0.020 REF.	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

Ordering Information

Device	Package	Shipping	
BAV16W	SOD-123	3000pcs / reel	
	(Pb-Free)	Souches / Teel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



T6 = Marking code

Carrier Tape Specification SOD-123



	SYMBOL	Millimeters		
		Min.	Max.	
	A	1.80	1.90	
	В	3.89	3.99	
	С	1.52	1.62	
	d	1.45	1.65	
	E	1.65	1.85	
	F	3.40	3.60	
	Р	3.90	4.10	
	P0	3.90	4.10	
	P1	1.90	2.10	
	W	7.90	8.30	





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